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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Preferred Device

Sensitive Gate Silicon Controlled Rectifiers Reverse Blocking Thyristors

PNPN devices designed for high volume, low cost consumer applications such as temperature, light and speed control; process and remote control; and warning systems where reliability of operation is critical.

Features

- Small Size
- Passivated Die Surface for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Recommend Electrical Replacement for C106
- Surface Mount Package Case 369C
- To Obtain "DPAK" in Straight Lead Version (Shipped in Sleeves): Add '1' Suffix to Device Number, i.e., MCR706A1
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

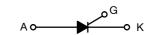
MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

| Rating | Symbol | Max | Unit |
|--|---------------------------------------|-------------------|--------------------|
| $\begin{tabular}{lllllllllllllllllllllllllllllllllll$ | V _{DRM,} V _{RRM} | 100 400 600 | V |
| | V _{RSM} | 150 450 650 | > |
| On–State RMS Current (180° Conduction Angles; T _C = 90°C) | I _{T(RMS)} | 4.0 | Α |
| Average On–State Current (180 $^{\circ}$ Conduction Angles) $T_C = -40 \text{ to } +90 ^{\circ}\text{C}$ $T_C = +100 ^{\circ}\text{C}$ | I _{T(AV)} | 2.6 1.6 | Α |
| Non-Repetitive Surge Current (1/2 Sine Wave, 60 Hz, T _J = 110°C) (1/2 Sine Wave, 1.5 ms, T _J = 110°C) | I _{TSM} | 25 35 | Α |
| Circuit Fusing (t = 8.3 msec) | l ² t | 2.6 | A ² sec |
| Forward Peak Gate Power (Pulse Width ≤ 1.0 μsec, T _C = 90°C) | P _{GM} | 0.5 | W |
| Forward Average Gate Power (t = 8.3 msec, T _C = 90°C) | P _{G(AV)} | 0.1 | W |
| Forward Peak Gate Current (Pulse Width ≤ 1.0 µsec, T _C = 90°C) | I _{GM} | 0.2 | Α |
| Operating Junction Temperature Range | TJ | -40 to +110 | °C |
| Storage Temperature Range | T _{stg} | -40 to +150 | °C |



Littelfuse.com

SCRs 4.0 AMPERES RMS 100 – 600 VOLTS



MARKING DIAGRAMS

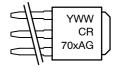


DPAK CASE 369C STYLE 5





DPAK-3 CASE 369D STYLE 5



| PIN ASSIGNMENT | | | |
|----------------|-----------|--|--|
| 1 Gate | | | |
| 2 | Anode | | |
| 3 | 3 Cathode | | |
| 4 | Anode | | |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction-to-Case | $R_{	heta JC}$ | 3.0 | °C/W |
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 80 | °C/W |
| Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds | TL | 260 | °C |

^{2.} Case 369C when surface mounted on minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Тур | Max | Unit | |
|---|---|-------------------------------------|--------|-----------|------------|----|
| OFF CHARACTERISTICS | | | • | | • | |
| Peak Repetitive Forward or Reverse Blocking Current (V_{AK} = Rated V_{DRM} or V_{RRM} ; R_{GK} = 1 k Ω) | T _C = 25°C T _C = 110°C | I _{DRM} , I _{RRM} | - - | - - | 10 200 | μΑ |
| ON CHARACTERISTICS | | | | | | |
| Peak Forward "On" Voltage (I _{TM} = 8.2 A Peak, Pulse Width = 1 to 2 ms, 2% Duty Cyc | :le) | V _{TM} | - | - | 2.2 | V |
| Gate Trigger Current (Continuous dc) (Note 3) (V _{AK} = 12 Vd | c, $R_L = 24 \Omega$) $T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$ | I _{GT} | - - | 25 - | 75 300 | μΑ |
| Gate Trigger Voltage (Continuous dc) (Note 3) $(V_{AK} = 12 \text{ Vdc}, R_L = 24 \Omega)$ | $T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$ | V _{GT} | - - | - - | 0.8 1.0 | V |
| Gate Non-Trigger Voltage (Note 3) ($V_{AK} = 12 \text{ Vdc}, R_L = 100$ | Ω , T _C = 110°C) | V_{GD} | 0.2 | - | - | V |
| Holding Current (V_{AK} = 12 Vdc, R_{GK} = 1 k Ω) T_{C} = 25°C (Initiating Current = 20 mA) T_{C} = -40°C | lΗ | - - | _ _ | 5.0 10 | mA | |
| Peak Reverse Gate Blocking Voltage (I _{GR} = 10 μA) | V_{RGM} | 10 | 12.5 | 18 | V | |
| Peak Reverse Gate Blocking Current (V _{GR} = 10 V) | | I _{RGM} | - | - | 1.2 | μΑ |
| Total Turn-On Time (Source Voltage = 12 V, R_S = 6 k Ω) (I_{TM} = 8.2 A, I_{GT} = 2 mA, Rated V _{DRM}) (Rise Time = 20 ns, F | Pulse Width = 10 μs) | t _{gt} | - | 2.0 | - | μs |
| DYNAMIC CHARACTERISTICS | | | | • | | |
| Critical Rate of Rise of Off–State Voltage (V_D = Rated V_{DRM} , R_{GK} = 1 k Ω , Exponential Waveform, | dv/dt | - | 10 | - | V/μs | |
| Repetitive Critical Rate of Rise of On–State Current (Cf = 60 Hz, I_{PK} = 30 A, PW = 100 μ s, diG/dt = 1 A/ μ s) | di/dt | - | - | 100 | A/μs | |
| | | | | • | • | |

^{3.} R_{GK} current not included in measurement.

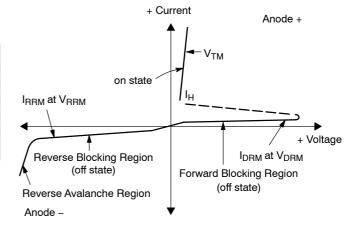
ORDERING INFORMATION

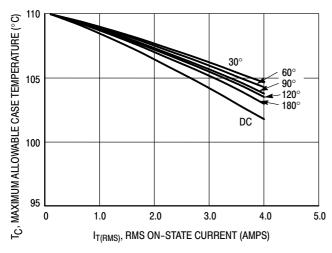
| Device | Package Type | Package | Shipping |
|------------|--------------|-------------------|------------------|
| MCR703AT4 | DPAK | 369C | 2500 Tape & Reel |
| MCR703AT4G | DPAK | 369C (Pb-Free) | 2500 Tape & Reel |
| MCR706AT4 | DPAK | 369C | 2500 Tape & Reel |
| MCR706AT4G | DPAK | 369C (Pb-Free) | 2500 Tape & Reel |
| MCR708A | DPAK | 369C | 75 Units / Rail |
| MCR708AG | DPAK | 369C (Pb-Free) | 75 Units / Rail |
| MCR708A1 | DPAK-3 | 369D | 75 Units / Rail |
| MCR708A1G | DPAK-3 | 369D (Pb-Free) | 75 Units / Rail |
| MCR708AT4 | DPAK | 369C | 2500 Tape & Reel |
| MCR708AT4G | DPAK | 369C (Pb-Free) | 2500 Tape & Reel |

5.0

Voltage Current Characteristic of SCR

| Symbol | Parameter |
|------------------|---|
| V_{DRM} | Peak Repetitive Off-State Forward Voltage |
| I _{DRM} | Peak Forward Blocking Current |
| V_{RRM} | Peak Repetitive Off-State Reverse Voltage |
| I _{RRM} | Peak Reverse Blocking Current |
| V_{TM} | Peak On-State Voltage |
| I _H | Holding Current |

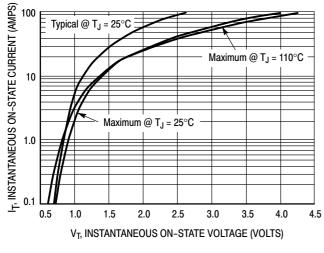




P(AV), AVERAGE POWER DISSIPATION (WATTS) DC 4.0 180° 120° 3.0 60° 2.0 30° 1.0 0 2.0 4.0 3.0 5.0 I_{T(RMS)}, RMS ON-STATE CURRENT (AMPS)

Figure 1. RMS Current Derating

Figure 2. On-State Power Dissipation



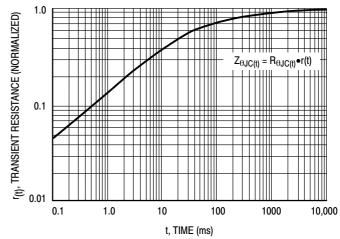


Figure 3. On-State Characteristics

Figure 4. Transient Thermal Response

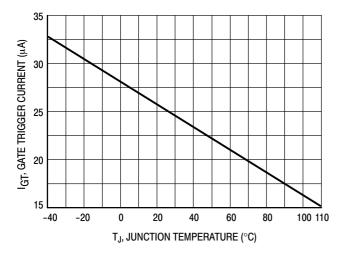


Figure 5. Typical Gate Trigger Current versus Junction Temperature

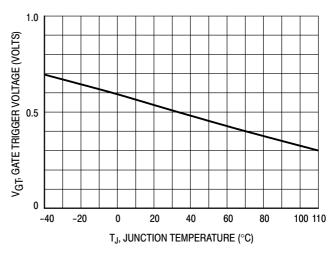


Figure 6. Typical Gate Trigger Voltage versus
Junction Temperature

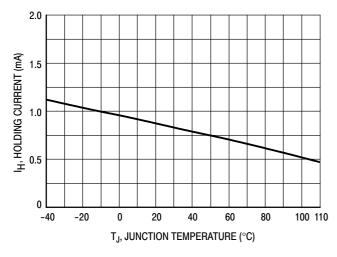


Figure 7. Typical Holding Current versus Junction Temperature

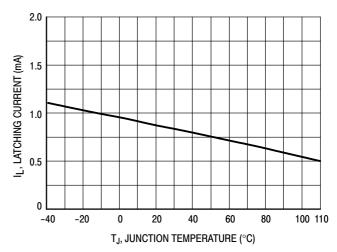
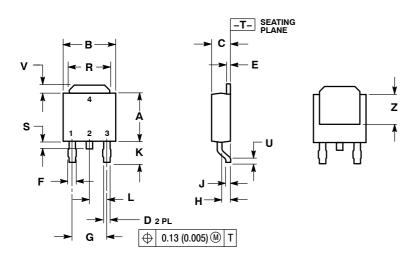


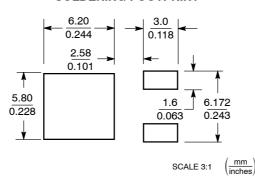
Figure 8. Typical Latching Current versus Junction Temperature

PACKAGE DIMENSIONS

DPAK CASE 369C-01 **ISSUE A**



SOLDERING FOOTPRINT



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

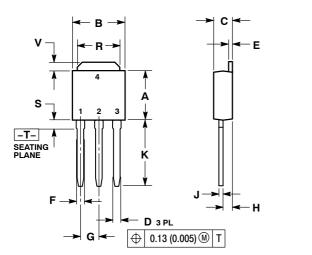
| | INC | NCHES MILLIMETER | | IETERS |
|-----|-------|------------------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.235 | 0.245 | 5.97 | 6.22 |
| В | 0.250 | 0.265 | 6.35 | 6.73 |
| C | 0.086 | 0.094 | 2.19 | 2.38 |
| D | 0.027 | 0.035 | 0.69 | 0.88 |
| Е | 0.018 | 0.023 | 0.46 | 0.58 |
| F | 0.037 | 0.045 | 0.94 | 1.14 |
| G | 0.180 | BSC | 4.58 BSC | |
| Н | 0.034 | 0.040 | 0.87 | 1.01 |
| 7 | 0.018 | 0.023 | 0.46 | 0.58 |
| K | 0.102 | 0.114 | 2.60 | 2.89 |
| L | 0.090 | BSC | 2.29 BSC | |
| R | 0.180 | 0.215 | 4.57 | 5.45 |
| S | 0.025 | 0.040 | 0.63 | 1.01 |
| U | 0.020 | | 0.51 | |
| ٧ | 0.035 | 0.050 | 0.89 | 1.27 |
| Z | 0.155 | | 3.93 | |

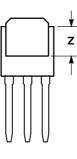
STYLE 5:

- PIN 1. GATE
 2. ANODE
 3. CATHODE
 4. ANODE

PACKAGE DIMENSIONS

DPAK-3 CASE 369D-01 **ISSUE B**





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

| $\overline{}$ | | | | | |
|---------------|--------|-------|------------|------|--|
| | INCHES | | MILLIMETER | | |
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.235 | 0.245 | 5.97 | 6.35 | |
| В | 0.250 | 0.265 | 6.35 | 6.73 | |
| С | 0.086 | 0.094 | 2.19 | 2.38 | |
| D | 0.027 | 0.035 | 0.69 | 0.88 | |
| Е | 0.018 | 0.023 | 0.46 | 0.58 | |
| F | 0.037 | 0.045 | 0.94 | 1.14 | |
| G | 0.090 | BSC | 2.29 BSC | | |
| Н | 0.034 | 0.040 | 0.87 | 1.01 | |
| J | 0.018 | 0.023 | 0.46 | 0.58 | |
| K | 0.350 | 0.380 | 8.89 | 9.65 | |
| R | 0.180 | 0.215 | 4.45 | 5.45 | |
| S | 0.025 | 0.040 | 0.63 | 1.01 | |
| ٧ | 0.035 | 0.050 | 0.89 | 1.27 | |
| Z | 0.155 | | 3.93 | | |

- STYLE 5: PIN 1. GATE 2. ANODE 3. CATHODE 4. ANODE

Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

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